

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
650V	60mΩ@10V	47A

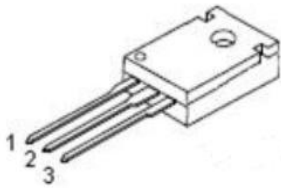
Feature

- Fast Switching
- Low Gate Charge and Rds(on)
- 100% Single Pulse avalanche energy Test

Applications

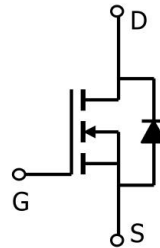
- PD charger
- Large screen display
- Telecom power
- Server power

Package

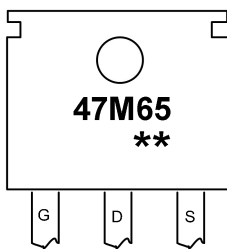


TO-247(1:G 2:D 3:S)

Circuit diagram



Marking



47M65 : Product code
****** : Week code

Absolute maximum ratings (Ta=25°C, unless otherwise noted)

Parameter	Symbol	Rating	Unit
Drain source voltage	V_{DS}	650	V
Gate source voltage	V_{GS}	± 30	V
Continuous drain current(Tc=25°C)	I_D	47	A
Continuous drain current(Tc=100°C)	I_D	29	A
Pulsed drain current	I_{DM}	188	A
Power dissipation(Tc=25°C)	P_D	391	W
Single pulsed avalanche energy ¹⁾	E_{AS}	1160	mJ
Thermal resistance, junction-case	$R_{\theta JC}$	0.32	°C/W
Operation and storage temperature	T_{stg}, T_j	-55 to 150	°C

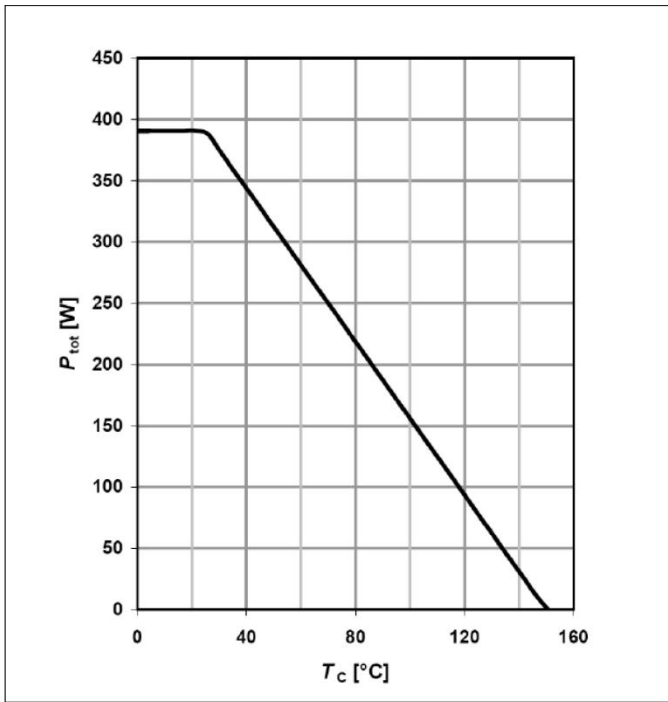
Electrical characteristics (Ta=25°C, unless otherwise noted)

Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = 250\mu A, V_{GS} = 0V$	650	-	-	V
Drain Cut-Off Current	I_{DSS}	$V_{DS} = 480V, V_{GS} = 0V$	-	-	1	μA
Gate Leakage Current	I_{GSS}	$V_{GS} = \pm 30V, V_{DS} = 0V$	-	-	± 0.1	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	3	4	V
Drain-Source ON Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 23A$	-	60	70	m Ω
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = 25V, V_{GS} = 0V, f = 1.0MHz$	-	3080	-	pF
Output Capacitance	C_{oss}		-	140	-	
Reverse Transfer Capacitance	C_{rss}		-	7	-	
Switching Characteristics						
Total Gate Charge	Q_g	$V_{DS} = 480V, V_{GS} = 10V, I_D = 23A$	-	194	-	nC
Gate-Source Charge	Q_{gs}		-	35	-	
Gate-Drain Charge	Q_{gd}		-	90	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{GS} = 10V, V_{DS} = 480V, I_D = 23A, R_G = 20\Omega$	-	22	-	ns
Rise Time	t_r		-	10	-	
Turn-Off Delay Time	$t_{d(off)}$		-	90	-	
Fall Time	t_f		-	5	-	
Drain-Source Body Diode Characteristics						
Source-Drain Diode Forward Voltage	V_{SD}	$I_S = 1A, V_{GS} = 0V$	-	-	1.2	V
Reverse Recovery Time	T_{rr}	$V_R = 400V, I_S = 10A, di/dt = 100A/\mu s$		527		ns

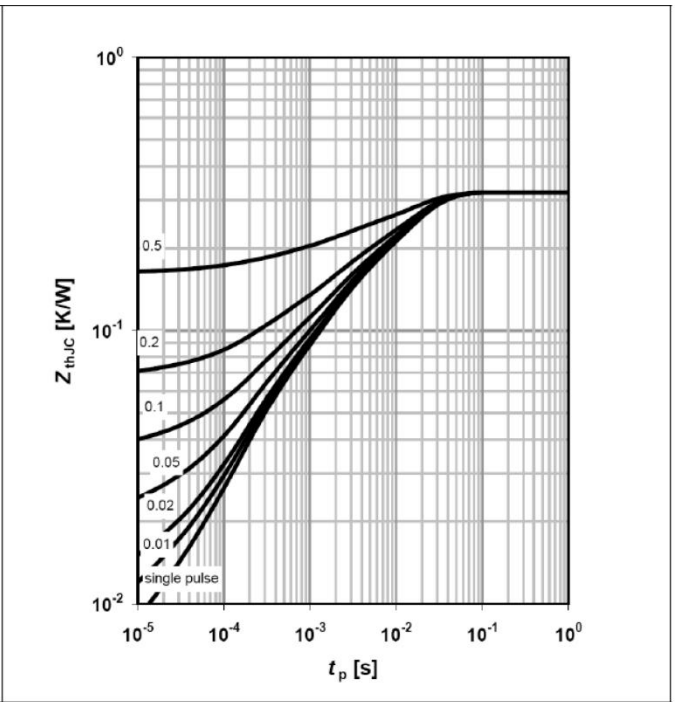
Note:

- E_{AS} is tested at starting $T_j = 25^\circ C, V_{DD} = 100V, V_{GS} = 10V, L = 0.5mH, R_g = 25\Omega$;

Typical Characteristics

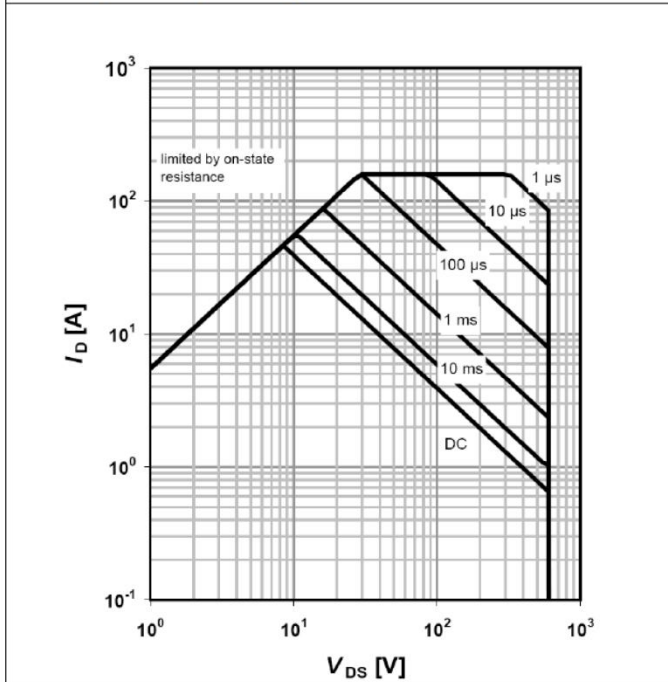


$P_{tot} = f(T_c)$



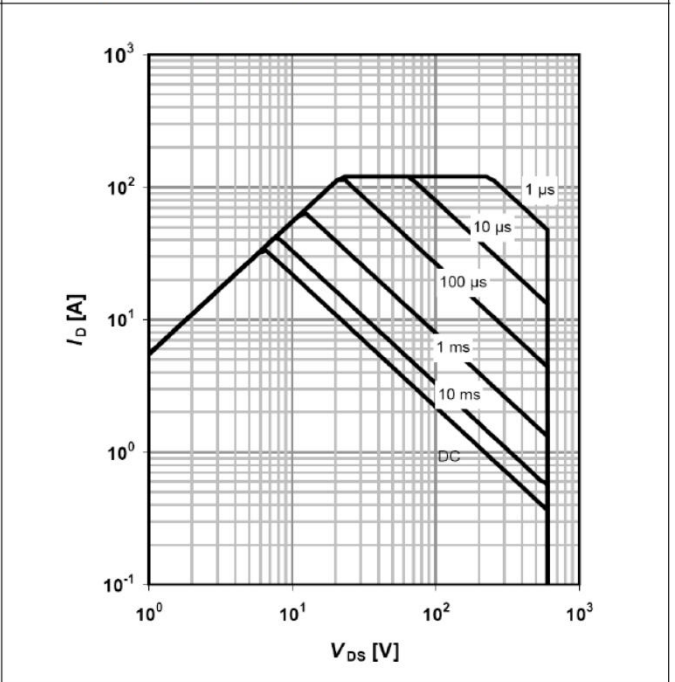
$Z_{(thJC)} = f(t_p)$; parameter: $D = t_p / T$

Safe operating area T_c=25 °C

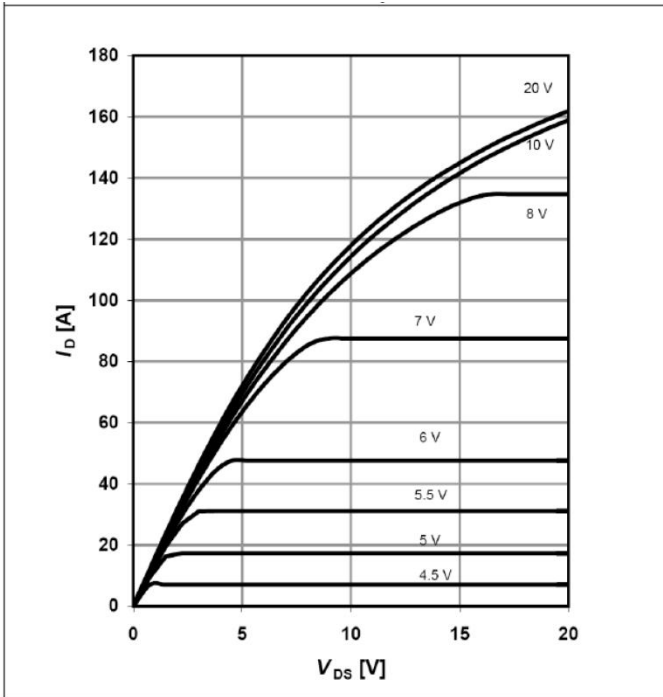


$I_D = f(V_{DS}); T_c = 25\text{ °C}; V_{GS} > 7V; D = 0$; parameter t_p

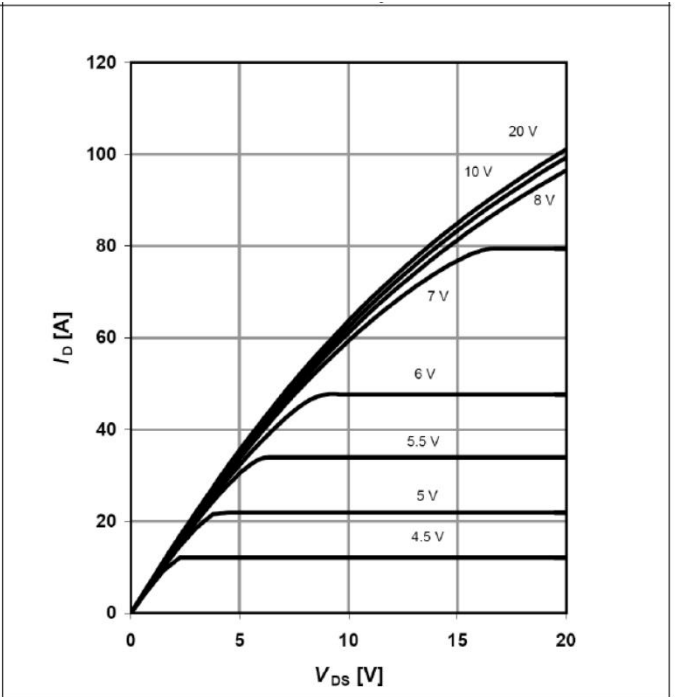
Safe operating area T_c=80 °C



$I_D = f(V_{DS}); T_c = 80\text{ °C}; V_{GS} > 7V; D = 0$; parameter t_p

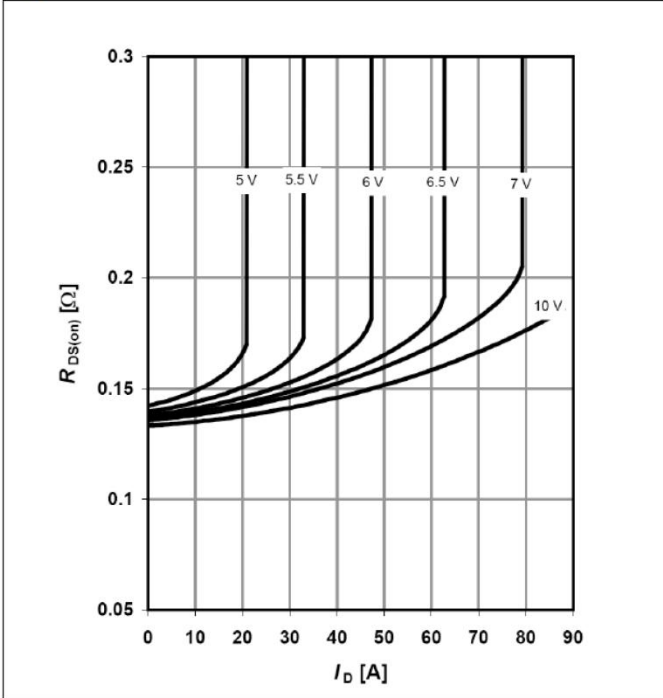


$I_D=f(V_{DS}); T_j=25\text{ }^\circ\text{C};$ parameter: V_{GS}



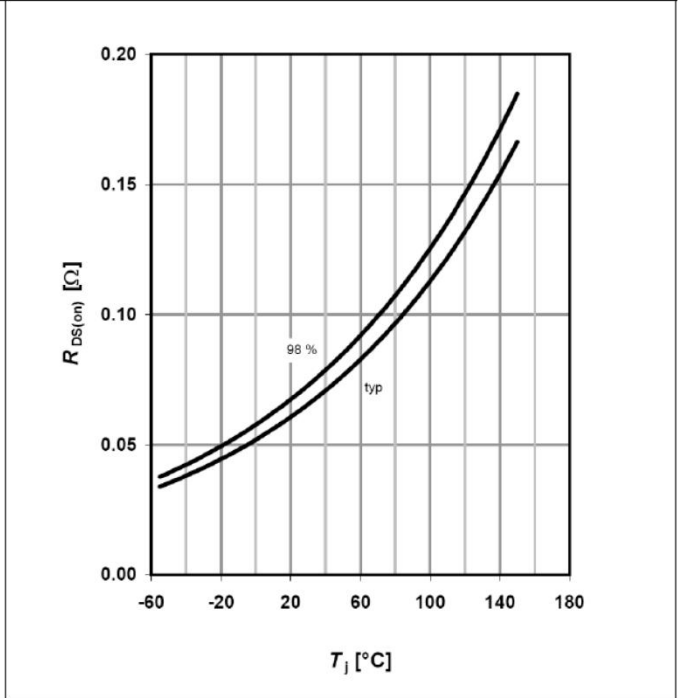
$I_D=f(V_{DS}); T_j=125\text{ }^\circ\text{C};$ parameter: V_{GS}

Typ. drain-source on-state resistance



$R_{DS(on)}=f(I_D); T_j=125\text{ }^\circ\text{C};$ parameter: V_{GS}

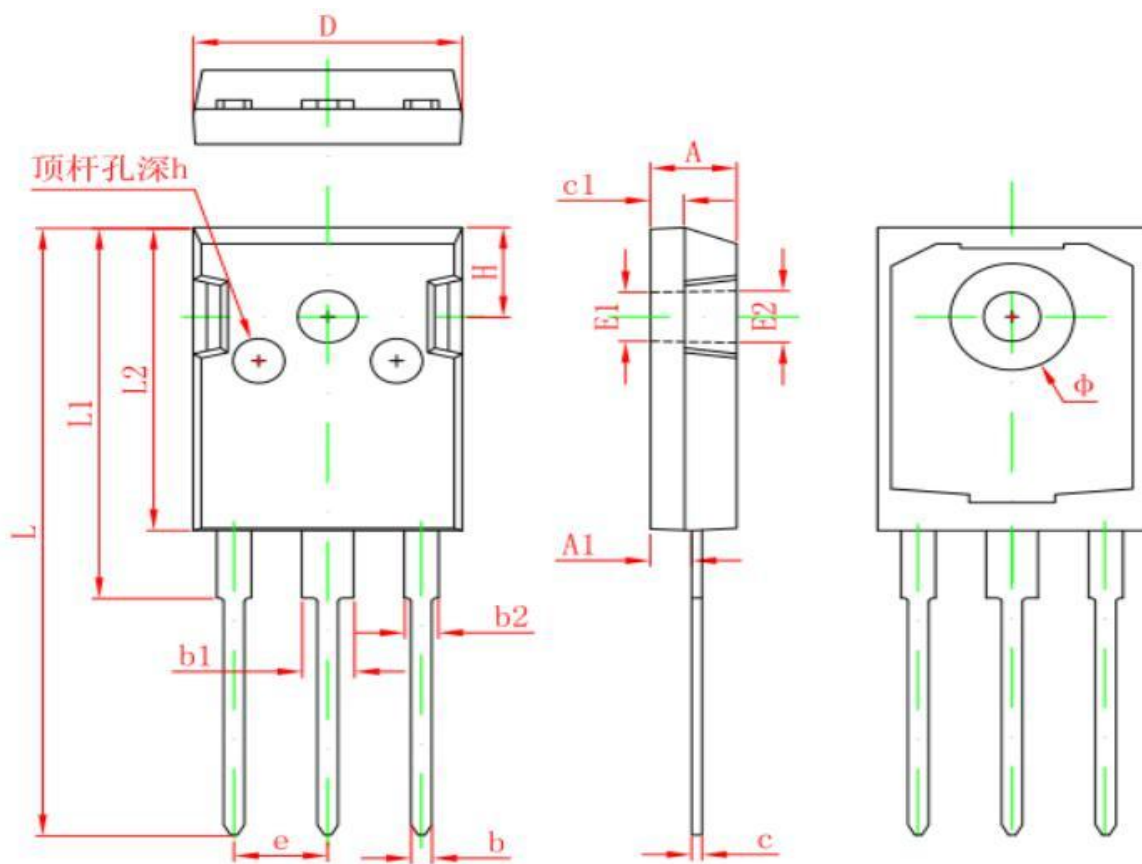
Drain-source on-state resistance



$R_{DS(on)}=f(T_j); I_D=17.6\text{ A}; V_{GS}=10\text{ V}$



TO-247 Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.850	5.150	0.191	0.200
A1	2.200	2.600	0.087	0.102
b	1.000	1.400	0.039	0.055
b1	2.800	3.200	0.110	0.126
b2	1.800	2.200	0.071	0.087
c	0.500	0.700	0.020	0.028
c1	1.900	2.100	0.075	0.083
D	15.450	15.750	0.608	0.620
E1	3.500 REF.		0.138 REF.	
E2	3.600 REF.		0.142 REF.	
L	40.900	41.300	1.610	1.626
L1	24.800	25.100	0.976	0.988
L2	20.300	20.600	0.799	0.811
Φ	7.100	7.300	0.280	0.287
e	5.450 TYP.		0.215 TYP.	
H	5.980 REF.		0.235 REF.	
h	0.000	0.300	0.000	0.012

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